

Title

Inotes

atomic structure } Bohr atomic model
 wave-mechanical model.

Quantum number (n, l, m_l, m_s)
 P19-21

Basic Information

Electron configuration.
 (P22-24)

Atomic Bonding in Solids

Chapter 1

Structure of Crystalline Solids

crystalline structure

single | poly-crystalline.

noncrystalline structure

lattice and unit cell

(APF=0.54) SC BCC FCC (APF=0.74)
 (APF=0.68)

Computation: Density ($\rho = \frac{nA}{V_c N_A}$), APF = $\frac{n \cdot \frac{4}{3} \pi r^3}{a^3}$

用 integral index

(P40-41) crystallographic directions and planes

(P48-49) Linear and Planar Density.

X, Y, Z 轴度量的
 比例数。

Distinguish:

science: develop or synthesize new materials
 engineer: create new products or system using existing materials.

Introduction: material science & engineer

Performance

Components: processing → structure → properties

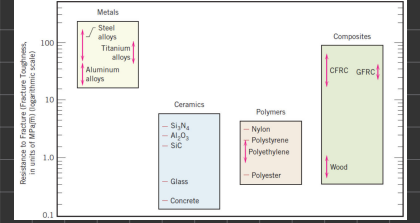
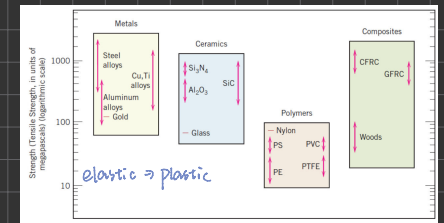
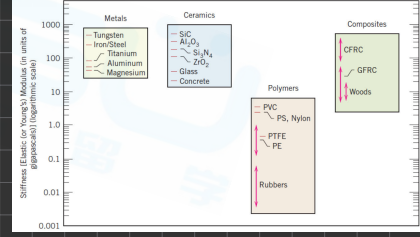
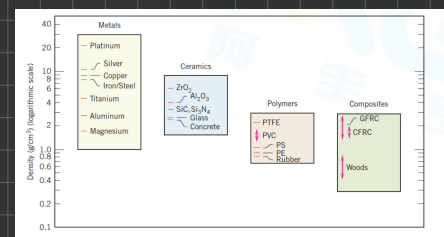
(mechanical, electrical, thermal, magnetic, optical, deteriorative)

变异性: 与化学环境相关。

Classification of Solid material

metal (P7) | ceramics (P8) | polymers (P9, 10). | composites (P11)

Comparison in Room-Temp.



elastic → plastic

Crystallographic Directions & Planes

①. Crystallographic Direction. $\Rightarrow$ 用方括号.

$\triangle [x\ y\ z]$: 以原点为起点, x, y, z 为 x, y, z 轴的 vector projection

若出现负值: 在数值上加 "-" eg: $-1 \Rightarrow \bar{1}$

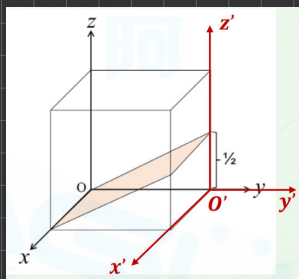
若出现分数 $\Rightarrow$ 乘最大倍数, 使 x, y, z 整数化.

②. Miller Indices: notation for crystal planes $\Rightarrow$ 用圆括号.

a) 确定面坐标的过程.

i). 看是否过原点, 若过原点则改变坐标系 $\Rightarrow$ ii). 找面在 x, y, z 轴上的投影, 取其倒数.

eg:



$\triangle$ 若和某坐标轴平行, 则投影为 ∞ , 倒数为 0.

$\Downarrow$

iii) 把所有坐标均化为整数.

b). 两个 Miller index 相同的面间距: $d = \frac{a}{\sqrt{h^2 + k^2 + l^2}}$
设 $(h\ k\ l)$

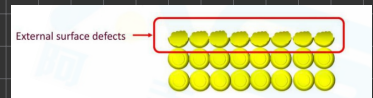
Chapter 2 Imperfection in Solids

Line / Linear Defect (1维)

- Types of dislocation
 - ① Edge dislocation (1/2)b
 - ② screw dislocation (1/1)b
 - ③ mixed dislocations (同时有 screw 和 edge)
- (l: dislocation line.
b: burger vector).

Burger vector ($\vec{b}$)
(与 slip 方向平行, 可以想象成和施加的外力平行的方向)

dislocation line ($\vec{l}$)
(垂直)



External surfaces
(表面原子没有邻居和它原子结合).

Plan Defect (2维)

(interfacial Defect).

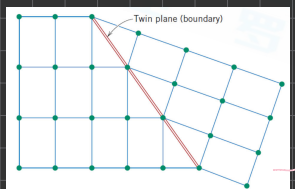
(特点: 能导向 ≠ 不反应)

Grain boundaries defect.
Grain boundary
(两个具有不同的晶体方向的晶粒间的边界).

defect 产生原因: 边界原子由于晶粒的方向不同而没有匹配上.

△特点: 可以被光学显微镜及精度更小的显微镜观测到. 不反应, 即不发生化学反应.

Twin boundaries.
(mirror lattice symmetry)



△形成于施加 shear forces.

twin boundary and the adjacent atom positions

boundaries between two phases

(3维) Bulk (volume) Defect.

small spaces are empty.

broken
pores, cracks, foreign inclusion, other phases
include impurity.

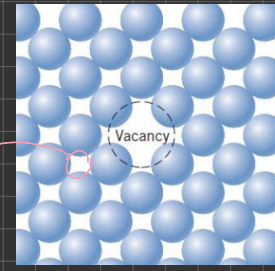
Point defect (0维)

⇒ 指一个/两个原子.

substitutional impurity atom

△区分 interstice 和 vacancy.

interstice.



① vacancy: $N_v = N \exp(-\frac{Q_v}{kT})$
energy required for formation of a vacancy
number of vacancy in equilibrium.

$N = \frac{N_A \cdot \rho}{A}$ (N: 每立方厘米的晶体中有 n 个原子. T: 开尔文温度.

(A: 相对原子质量. ρ : density). k: 玻尔兹曼常数. 数值为 $1.38 \times 10^{-23} \text{ J/K}$.

△ T < melting point 时 $N_v/N \approx 10^{-8}$.

②. concentration of absences: $\frac{N_v}{N} = \exp(-\frac{Q_v}{kT})$

(晶体中的原子被本身插入空隙)

self-interstitial
interstitial of impurity atom
(空隙中插入其它原子).

temperature, time dependent process.

- ①. material transport by atomic motion (in specific solid)
- ②. transport in different phases.

concept

Dependence

Basic information

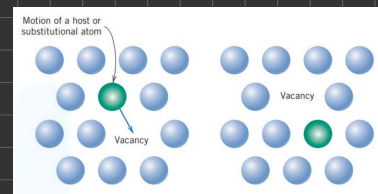
(具体见下页)
Calculation

Chapter 3 Diffusion

Bulk diffusion (caused by atomic motion).

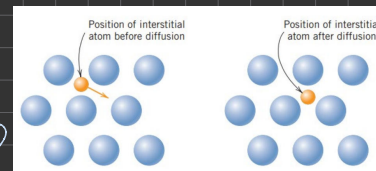
vacancies diffusion

(原子和相邻的vacancy交换位置)
Impurities 原子.



interstitial diffusion.

(Impurity 原子插入晶体内原子间隙中.)



△ 相较 vacancies diff. 更快发生: 所需能量小 ($Q_i < Q_v$).

Grain boundaries diffusion

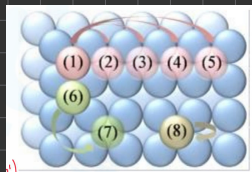
△ 特点: Grain 间有缺陷发展, 使得它发生的速率远大于 bulk diffusion (10⁶ times greater).

△ 当晶粒极小时, 该种 diffusion 起的作用极大.

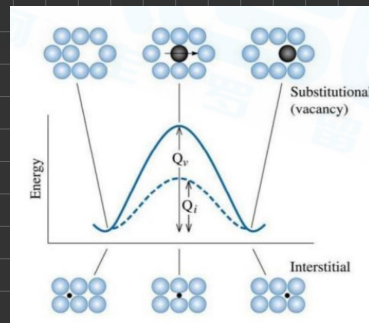
Surface diffusion

① 吸附表面原子 (adatoms) 和原子团簇 (atomic clusters) 运动

②. surface diffusion jump mechanisms



(三种不同的表面扩散的跳跃机制)



Chapter 3 计算.

eq: T , 浓度 C , t .

[给定右侧浓度时计算 diffusion flux, diffusion coefficient 及 相关量]

▷ diffusion is a time dependent process. (Fick's law)

Def

Diffusion flux (J): $J = \frac{M}{At} = \frac{1}{A} \frac{dM}{dt}$ ▷ 质量在面上的变化率.

⇒ $[J] = [kg/m^2 \cdot s]$ or $[atoms/m^2 \cdot s]$

①. Fick's 1st law (steady state diffusion).

使用条件: C 变化与 t 不相关. (or x 与 x 相关).

$$J = -D \frac{dC}{dx} \quad (J = -D \frac{C_2 - C_1}{\Delta x}). \quad D: \text{diffusion coefficient}$$

②. Fick's second law (non-steady). (C 与 t 相关)

$$\textcircled{1} \Delta \frac{\partial C}{\partial t} = D \frac{\partial^2 C}{\partial x^2} \quad (C \text{ 变化同时与 } t, x \text{ 相关})$$

用图表对应得到数值.

$$\textcircled{2} \frac{C_x - C_0}{C_s - C_0} = 1 - \text{erf}\left(\frac{x}{2\sqrt{Dt}}\right) \quad \text{erf}\left(\frac{x}{2\sqrt{Dt}}\right): \text{Gaussian error function}$$

C_0 : 假设 C_s : 开始时. C_x : 中间时刻浓度.

Table 5.1 Tabulation of Error Function Values

z	$\text{erf}(z)$	z	$\text{erf}(z)$	z	$\text{erf}(z)$
0	0	0.55	0.5633	1.3	0.9340
0.025	0.0282	0.60	0.6039	1.4	0.9523
0.05	0.0564	0.65	0.6420	1.5	0.9661
0.10	0.1125	0.70	0.6778	1.6	0.9763
0.15	0.1680	0.75	0.7112	1.7	0.9838
0.20	0.2227	0.80	0.7421	1.8	0.9891
0.25	0.2763	0.85	0.7707	1.9	0.9928
0.30	0.3286	0.90	0.7970	2.0	0.9953
0.35	0.3794	0.95	0.8209	2.2	0.9981
0.40	0.4284	1.0	0.8427	2.4	0.9993
0.45	0.4755	1.1	0.8802	2.6	0.9998
0.50	0.5205	1.2	0.9103	2.8	0.9999

▷ Diffusion coefficient

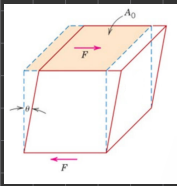
depends on atom $D = D_0 \exp\left(-\frac{Q_d}{RT}\right)$

Q_d : 原子挣脱 bond 发生 diffusion 所需的能量.

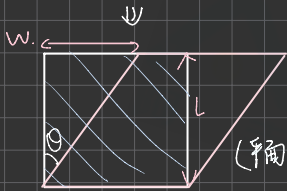
▷ D_0 : 在无限 activation energy 障碍情况下. 扩散的自限速率. 题目会给

T : 开尔文温度; $R = 8.314 \text{ J/mol} \cdot K$.

shear force
(施加于下面平行的力)



(侧视图)

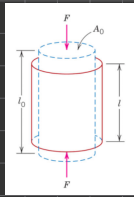


(平面图)

→ τ (stress)

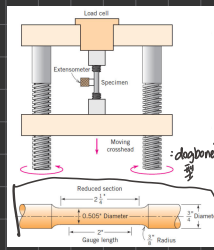
initial specimen

- A_0 : initial specimen area.
- shear stress (τ): $\tau = \frac{F}{A_0}$.
- shear strain: tangent of strain angle θ .



和 tensile test 类似, 但施加的是压力。

compressive test
压力



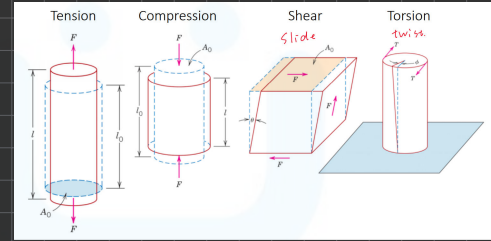
tensile test
拉力

- machine: 匀速拉伸样品, 测量-瞬时时刻下的力 (load) 和伸长量 (elongation)
- output: load, elongation
- 用于定义 σ (机械应力) 和 ϵ (机械应变)
engineer stress, engineer strain
力为 engineer σ , true σ .
- 样品需求 (specimen): 常为 cylindrical, "dogbone" 构型.

test

Concept: response to an applied load or force.

Type of loads:



(在力的影响下材料的不同反应)。

Chapter 4 ① Mechanical properties

Types: strength, hardness, ductility, stiffness

①. strength: 材料在外力作用下抵抗破坏或抵抗永久变形的能力 (用应力衡量)。

tensile strength

$$\sigma_t = \frac{F_t}{A_0}$$

A_0 : 试样的初始面积

yield strength

$$\sigma_y = \frac{F_y}{A_0}$$

σ_t, σ_c : 在 tensile 和 compressive test 中的最大应力。

compressive strength

$$\sigma_c = \frac{F_c}{A_0}$$

shear test 中,
shear strength

$$\tau = \frac{F_s}{A}$$

剪切截面积

②. hardness: 材料抵抗局部塑性变形的能力。 (eg: 凿入, 划痕, 压痕)。

③. stiffness: $k = \frac{F}{\Delta L}$ (F: 外力; ΔL : 外力产生的变形)

④. ductility: 表示材料在受到塑性形变下保持不破裂的性质。

Mohs hardness Test. (矿物学中的一种硬度测试方法)

- Mohs hardness: 定义为材料抵抗划痕的能力
- 通过 H 对材料 and 已知硬度的标准矿物确定硬度值。

△ 其他硬度测试方法

Table 6.5 Hardness-Testing Techniques				
Test	Indenter	Shape of Indentation	Load	Formula for Hardness Number
Brinell	10-mm sphere of steel or tungsten carbide	Side View: Top View:	P	$HB = \frac{2P}{\pi D(D - \sqrt{D^2 - d^2})}$
Vickers microhardness	Diamond pyramid	Side View: Top View:	P	$HV = 1.854P/d^2$
Knoop microhardness	Diamond pyramid	Side View: Top View:	P	$HK = 14.22P/d^2$
Rockwell and Superficial Rockwell	Diamond cone: 1/16 in. diameter steel spheres	Side View: Top View:	40 kg 100 kg 150 kg 15 kg 30 kg 45 kg	Rockwell Superficial Rockwell